## 1T-MoS<sub>2</sub>, a New Metallic Modification of Molybdenum Disulfide

## Fernando Wypych and Robert Schöllhorn\*

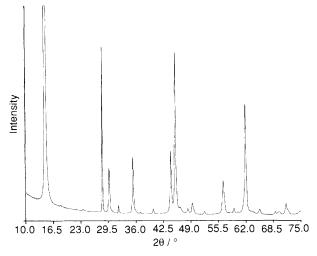
Technische Universität Berlin, Institut für Anorganische und Analytische Chemie, Strasse des 17. Juni 135, D-1000 Berlin 12, Germany

Hydration and subsequent electrochemical or chemical oxidation of potassium thiomolybdate( $\mathbf{m}$ ) KMoS<sub>2</sub> yields a new metastable and metallic modification of molybdenum disulfide with distorted layers and octahedral coordination to Mo atoms.

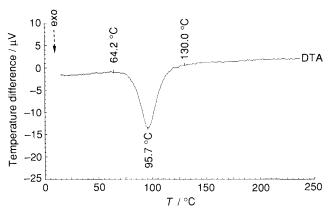
The structural chemistry and polytype formation of layered transition metal dichalcogenides of groups 4–6 have been the subject of intensive investigation in the last two decades. For the group 6 chalcogenides  $MoS_2$  and  $WS_2$ , both of which are major components of important heterogeneous catalyst systems, one stable 2H structure type has been observed which is characterized by neutral  $MS_2$  layers formed by trigonal prismatic  $MX_6$  units sharing edges; both phases are semicon-

ductors.<sup>1</sup> Recently the formation of an orthorhombic metastable polytype o-WS<sub>2</sub> has been reported, whose detailed structure is unknown so far.<sup>2</sup> We report here on the preparation and characterization of a new metastable metallic  $MoS_2$  polytype with a distorted layer structure and octahedral coordination of the metal atoms.

The synthesis started from the ternary phase potassium thiomolybdate(III)  $KMoS_2$  which has been described earlier.<sup>3</sup>



**Fig. 1** Powder X-ray diffraction pattern of  $1\text{T-MoS}_2$ ; the line at  $2\theta = 28.4^{\circ}$  belongs to the Si standard; minor lines or shoulders at  $2\theta = 35.8$ , 46.5 and 63.5° have not been indexed; (*hkl*) and experimental *d* values: (001) 5.999, (100) 4.850, (101) 3.776, (002) 2.998, (110) 2.799, (111) 2.537, (200) 2.423, (201) 2.246, (112) 2.045, (003) 1.998, (202) 1.884, (210) 1.832, (211) 1.753, (300) 1.616, (212) 1.561, (301) 1.561, (004) 1.498, (220) 1.399, (221) 1.363, (310) 1.343, (311) 1.311, (222) 1.267



**Fig. 2** DTA curve for 1T-MoS<sub>2</sub> showing the transition to disordered 2H-MoS<sub>2</sub> (heating rate 2 K min<sup>-1</sup>, argon atmosphere)

The preparation of the latter as a pure single phase has been achieved by the reaction of  $K_2MoO_4$  with dry hydrogen sulfide at 320 °C for 12 h and subsequently at 470 °C for 12 h. The resulting product was reduced at 850 °C with a mixture of H<sub>2</sub> and N<sub>2</sub> (20% vol and 80% vol, respectively) for 72 h to form black KMoS<sub>2</sub>. The latter was repeatedly washed with water until the suspension reached a pH of 7–8. The washing process is correlated with a partial oxidation of KMoS<sub>2</sub> under formation of hydrogen and a simultaneous hydration process [eqn. (1)].

$$KMoS_2 + (x + y) H_2O \rightarrow K_{1-x}(H_2O)_yMoS_2 + x KOH + x/2 H_2$$
(1)

The analytical composition of the air dried product is  $K_{0.33}(H_2O)_{0.6}MoS_2$  (monoclinic lattice parameters are  $a = 570.0 \pm 0.1$ ,  $b = 323.8 \pm 0.1$ ,  $c = 946.0 \pm 0.2$  pm,  $\beta = 100.54 \pm 0.03^{\circ}$ ). The hydrated layered chalcogenide was thereafter oxidized by chemical means (*e.g.* aqueous  $K_2Cr_2O_7$  in 0.05 mol dm<sup>-3</sup> H<sub>2</sub>SO<sub>4</sub>; MeCN-I<sub>2</sub>) or by galvanostatic anodic oxidation of pressed polycrystalline electrodes in aqueous  $K_2SO_4$  electrolyte [eqn. (2)]. After washing with water and  $K_{0.33}(H_2O)_{0.6}MoS_2 \rightarrow MoS_2 + 0.33 e^-$ 

$$H_2O_{0.6}MOS_2 \rightarrow MOS_2 + 0.55 \text{ e} + 0.6 \text{ H}_2\text{O} + 0.33 \text{ K}^+ \quad (2)$$

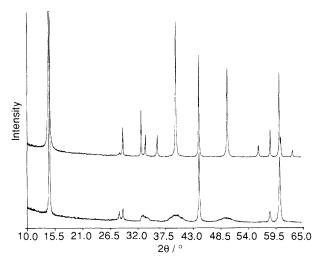


Fig. 3 Powder X-ray diffraction pattern of disordered  $2H-MoS_2$  obtained after the phase transition  $1T \rightarrow 2H$  (lower curve); powder diffraction pattern of crystalline  $2H-MoS_2$  (upper curve) obtained on extended annealing

drying at  $10^{-3}$  Torr/300 K (1 Torr = 133.322 Pa) a bronze coloured single phase product I was obtained; analytical data confirmed the presence of a binary phase with a ratio Mo:S ca. 1:2. The powder X-ray diffraction diagram (Siemens D 500 diffractometer, Cu-K $\alpha_1$  radiation) obtained in reflection mode is given in Fig. 1; the texture effect of the layered compound results in high intensities of the basal reflections. The hexagonal lattice parameters of I were determined by Guinier photographs and correspond to  $a = 559.7 \pm 0.1$ , c =599.4  $\pm$  0.1 pm. The small line width of the Bragg reflections demonstrates the high crystallinity and low defect concentration of I. According to conventional simple polytype notation I is therefore to be described as  $1T-MoS_2$ . The relation between the unit cells of 1T-MoS<sub>2</sub> and 2H-MoS<sub>2</sub> is  $a_{1T} \simeq a_{2H}$  $\sqrt{3}$  and  $c_{1T} \simeq 1/2 c_{2H}$ . Differential thermal analysis (DTA) in argon atmosphere and X-ray data show that 1T-MoS<sub>2</sub> is a metastable compound that undergoes an irreversible phase transition at constant mass at 95 °C to disordered 2H-MoS<sub>2</sub>. The thermal phase change is shown in Fig. 2. The 2H-phase obtained without annealing displays rotational disorder with sharp 001, 100 and 110 reflections while the mixed reflections 10l are strongly broadened (Fig. 3: lower curve). Extended annealing at a temperature of 900 °C yields the powder pattern of well crystalline 2H-MoS<sub>2</sub> (Fig. 3: upper curve).

Preliminary single crystal X-ray data of 1T-MoS<sub>2</sub> indicate that the compound has a distorted layer type structure; in contrast with 2H-MoS<sub>2</sub> where the molybdenum atoms are located in trigonal prismatic sites, the coordination of the metal atoms in 1T-MoS<sub>2</sub> is octahedral.<sup>4</sup> The sulfur atoms appear to be displaced from their ideal positions in the (001) direction which results in a superstructure  $a\sqrt{3} \times a\sqrt{3}$ .

In agreement with a recent theoretical band structure calculation,<sup>5</sup> we found a negative temperature coefficient for the electronic conductivity of 1T-MoS<sub>2</sub> and Pauli paramagnetism. In contrast with the semiconducting properties of 2H-MoS<sub>2</sub> the new phase is thus a metal. The structural and electronic distortions induce similarly strong consequences for the chemical reactivity: while 2H-MoS<sub>2</sub> (Fermi level in d band gap) does form highly unstable intercalation compounds with very low electrochemical potentials, the polytype 1T-MoS<sub>2</sub> (Fermi level within the d band) is easily accessible for all electron/ion transfer and exchange reactions described earlier for layered transition metal dichalcogenides MX<sub>2</sub> of groups 4 and 5;<sup>6</sup> the compounds obtained from 1T-MoS<sub>2</sub> are rather stable in air at room temperature owing to the higher

electrochemical potential of the distorted  $(MoS_2)^{x-}$  layer units.7 The intercalated phases are monoclinic with one MoS<sub>2</sub> layer per unit cell and show high crystallinity. It is interesting to compare these compounds with those obtained by direct intercalation of 2H-MoS<sub>2</sub>, e.g. solvated phases<sup>8.9</sup> or Li<sub>x</sub>MoS<sub>2</sub>.<sup>10,11</sup> The lithium phases also show distorted structures; their properties and structural details appear, however, not to be identical with those of the phases derived from IT-MoS<sub>2</sub>. Further investigations by us showed that related dichalcogenides 2M-WS<sub>2</sub> and 1T-Mo<sub>0.5</sub>W<sub>0.5</sub>S<sub>2</sub> with distorted structures can be obtained in a similar way.7 Since intercalation compounds with Ni and Co can be prepared from the binary phases by intercalation, it should be useful to compare their catalytic properties with those of the Ni and Co doped hydrodesulfurization catalysts derived from the stable 2H polytypes.

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